

MOSFETs FOR INDUSTRIAL APPLICATIONS LOW VOLTAGE MOSFETs IN TRANSISTOR OUTLINE (TO-) PACKAGES

Breakdown Voltages: -200 V to 250 V

Selected Products Industry Low R_{DS(ON)} and the Best R_{DS} - Q_{DSS} FOM







SUM70101EL -100 V, < 10.1 mΩ

D2PAK

SUG90090E 200 V. < 9.5 mΩ T0-247

SUP90142E

200 V.

Best R_{ns}-Q_{nss}

T0-220

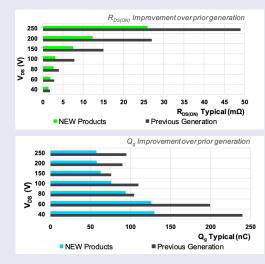
30 % Lower R_{DS(0N)} than products from prior generation

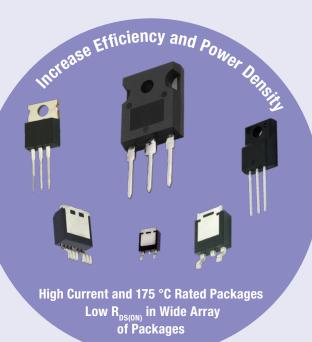
150 V

< **5.4** mΩ

T0-247

Improved Q_a reduces power loss from switching





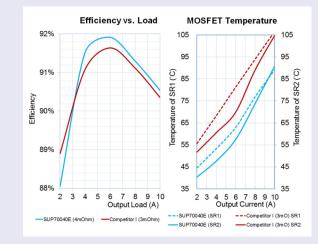
EXTENSIVE ARRAY OF PACKAGE OPTIONS AND FEATURES

Selected products are optimized for 5 V gate drive operations with low R_{DS(ON)}

T0-247	T0-220F	T0-220	D2PAK	D2PAK-7L	DPAK
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Up to 100 A	Up to 56 A	Up to 120 A	Up to 120 A	Up to 200 A	Up to 50 A

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MORE EFFICIENT Power Delivery **COOLER** Temperature During Operation **PREVENTS** Overheating



APPI ICATIONS

- Telecom Equipment
- Power Tools
- Power Supplies
- Motor Drive Control
- Renewable Energy
- Battery Management



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